


APPLICATION DATA SHEET

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Title of Invention	[SPLIT GATE FLASH MEMORY CELL AND MANUFACTURING METHOD THEREOF]	
Application Type : regular, utility Attorney Docket Number : 11080-US-PA		
Correspondence address: Customer Number: 31561 		
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Inventors Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr. Given Name: TZU-CHING Family Name: TSAI Residence: City of Residence: TAOYUAN Country of Residence: TW Address-1 of Mailing Address: 10FL.-9, NO. 39, NANHUA 1ST ST., LUJU SHIANG Address-2 of Mailing Address: City of Mailing Address: TAOYUAN State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail: <u>Inventor 2:</u> Applicant Authority Type: Inventor		

Citizenship:	TW
Name prefix:	Mr.
Given Name:	YI-NAN
Family Name:	CHEN
Residence:	
City of Residence:	TAIPEI CITY
Country of Residence:	TW
Address-1 of Mailing Address:	NO. 4, LANE 151, JIANMIN RD., BEITOU DISTRICT
Address-2 of Mailing Address:	
City of Mailing Address:	TAIPEI CITY
State of Mailing Address:	
Postal Code of Mailing Address:	
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	

Attorney Information:

practitioner(s) at Customer Number:

31561



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.